



DMP610DL

#### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	ID TA = +25°C
-60V	10Ω @ V <sub>GS</sub> = -5V	-180mA

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General purpose interfacing switches
- Power management functions
- Analog switches

# Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

P-CHANNEL ENHANCEMENT MODE MOSFET

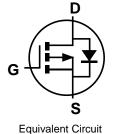
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (<u>DMP610DLQ</u>)

#### **Mechanical Data**

- Package: SOT23
- Package Material: UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (Lead Free Plating).
  Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Top View





Top View

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#### Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMP610DL-7	SOT23	3,000	Tape & Reel	
DMP610DL-13	SOT23	10,000	Tape & Reel	

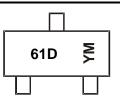
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



 $\begin{array}{l} 61D = \mbox{Product Type Marking Code} \\ YM = \mbox{Date Code Marking} \\ Y \mbox{ or } \overline{Y} = \mbox{Year (ex: K = 2023)} \\ M = \mbox{Month (ex: 9 = September)} \end{array}$ 

Date Code Key

Year	2016		2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	D		К	L	М	Ν	0	Р	R	S	Т	U
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		Vdss	-60	V	
Gate-Source Voltage			V <sub>GSS</sub>	±30	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = -5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	-180 -130	mA
Maximum Continuous Body Diode Forward Curren	nt (Note 6)	ls	-0.5	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)		Ідм	-1.2	А

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	310	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	405	°C/W
Total Power Dissipation (Note 6)	·	PD	500	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	251	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						·
Drain-Source Breakdown Voltage	BVDSS	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μA	$V_{DS} = -60V, V_{GS} = 0V$
Gate-Source Leakage	Igss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	-0.8	—	-2.0	V	$V_{DS} = V_{GS}, I_D = -1mA$
Static Drain-Source On-Resistance	RDS(ON)		_	10	Ω	V <sub>GS</sub> = -5V, I <sub>D</sub> = -0.1A
Forward Transconductance	<b>g</b> fs		0.25	_	S	V <sub>DS</sub> = -25V, I <sub>D</sub> = -0.1A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	24.6	—	pF	
Output Capacitance	Coss		4.8	_	pF	V <sub>DS</sub> = -25V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	2.8	_	pF	
Gate Resistance	Rg	_	242		Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = -4.5V)	QG		280	_	рС	
Total Gate Charge (V <sub>GS</sub> = -10V)	Q <sub>G</sub>	_	560		рС	)/= = 10)/_  = 100m A
Gate-Source Charge	Qgs		90	_	рС	V <sub>DS</sub> = -10V, I <sub>D</sub> = -100mA
Gate-Drain Charge	Qgd	_	77		рС	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	2.8	_	ns	
Turn-On Rise Time	tR	_	2.6		ns	V <sub>DD</sub> = -30V, I <sub>D</sub> = -0.27A,
Turn-Off Delay Time	tD(OFF)	_	11.1		ns	$R_{GEN} = 50\Omega$ , $V_{GS} = -10V$
Turn-Off Fall Time	tF		7.2		ns	7

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

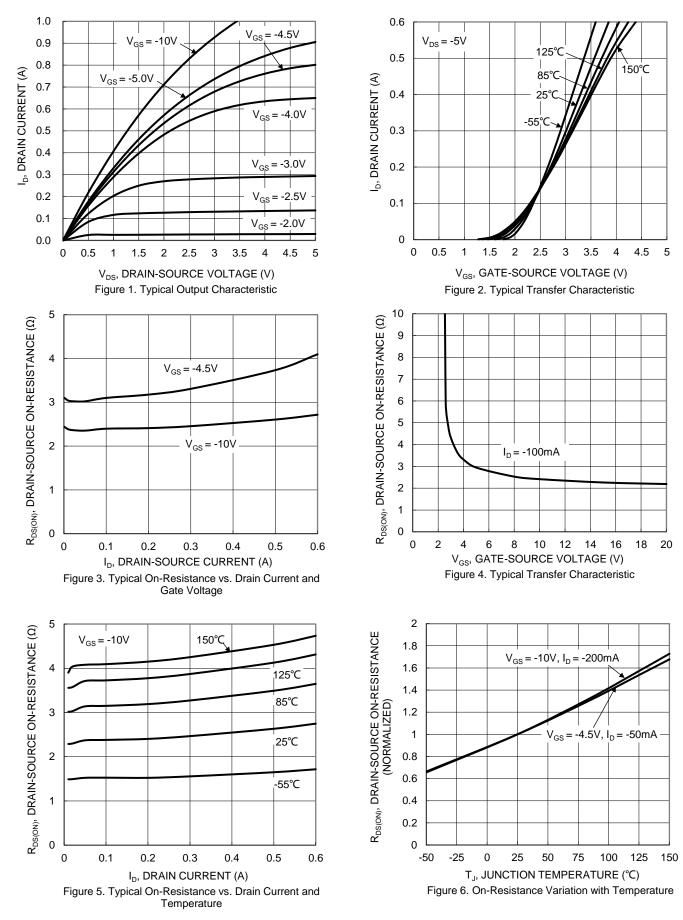
6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. copper, single sided.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

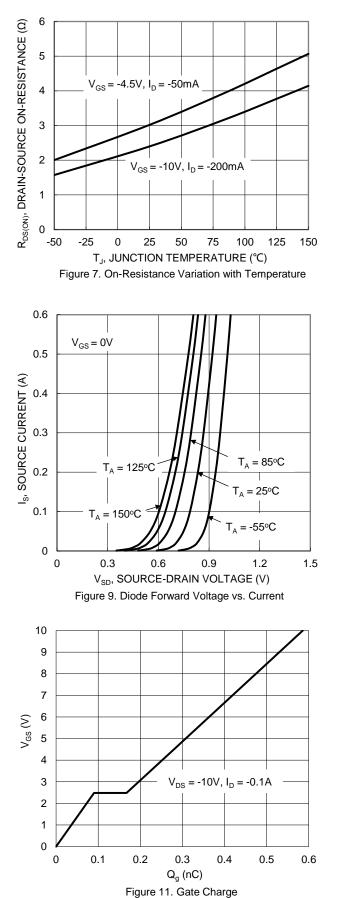


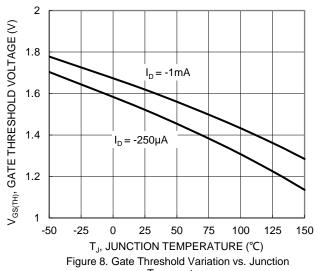
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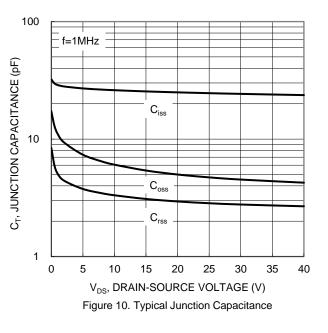


#### DMP610DL

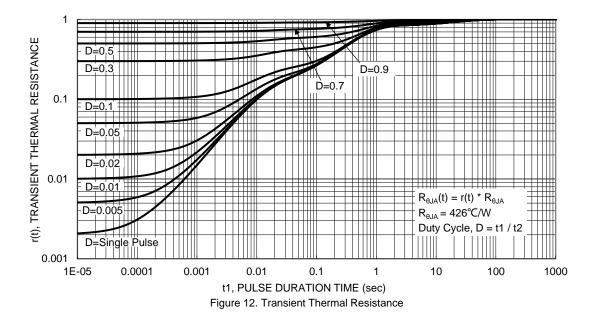








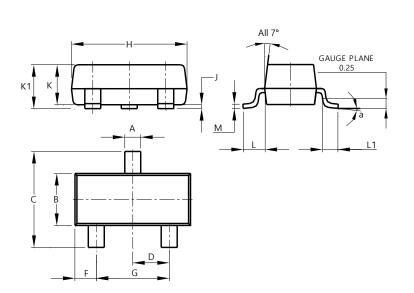






# **Package Outline Dimensions**

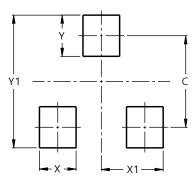
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
в	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
К	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	
All	Dimens	ions in	mm

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23
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Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

# SOT23



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